ANALOG DEVICES

4 Ω R$_{ON}$, 4-/8-Channel, ±15 V/+12 V/±5 V *i*CMOS Multiplexers

Data Sheet

ADG1408/ADG1409

FEATURES

4.7 Ω maximum on resistance at 25°C
0.5 Ω on-resistance flatness
Up to 190 mA continuous current
Fully specified at ±15 V/+12 V/±5 V
3 V logic-compatible inputs
Rail-to-rail operation
Break-before-make switching action
16-lead TSSOP and 4 mm × 4 mm LFCSP

APPLICATIONS

Relay replacement
Audio and video routing
Automatic test equipment
Data acquisition systems
Temperature measurement systems
Avionics
Battery-powered systems
Communication systems
Medical equipment

GENERAL DESCRIPTION

The ADG1408/ADG1409 are monolithic *i*CMOS® analog multiplexers comprising eight single channels and four differential channels, respectively. The ADG1408 switches one of eight inputs to a common output, as determined by the 3-bit binary address lines, A0, A1, and A2. The ADG1409 switches one of four differential inputs to a common differential output, as determined by the 2-bit binary address lines, A0 and A1. An EN input on both devices is used to enable or disable the device. When disabled, all channels are switched off.

The industrial CMOS (*i*CMOS) modular manufacturing process combines high voltage complementary metal-oxide semiconductor (CMOS) and bipolar technologies. It enables the development of a wide range of high performance analog ICs capable of 33 V operation in a footprint that no other generation of high voltage devices has been able to achieve. Unlike analog ICs using conventional CMOS processes, *i*CMOS components can tolerate high supply voltages while providing increased performance, dramatically lower power consumption, and reduced package size.
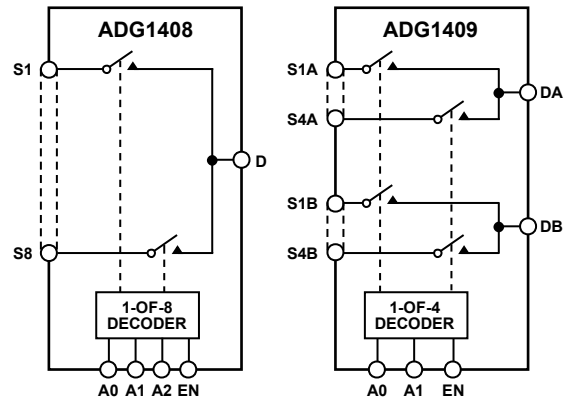
FUNCTIONAL BLOCK DIAGRAMS

Figure 1.

The ultralow on resistance and on resistance flatness of these switches make them ideal solutions for data acquisition and gain switching applications where low distortion is critical. *i*CMOS construction ensures ultralow power dissipation, making the devices ideally suited for portable and battery-powered instruments.

PRODUCT HIGHLIGHTS

1. 4 Ω on resistance.
2. 0.5 Ω on-resistance flatness.
3. 3 V logic compatible digital input, V$_{IH}$ = 2.0 V, V$_{IL}$ = 0.8 V.
4. 16-lead TSSOP and 4 mm × 4 mm LFCSP.

Table 1. Related Devices

Device No.	Description
ADG1208/ADG1209	Low capacitance, low charge injection, and low leakage 4-/8-channel ±15 V multiplexers

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REVISION HISTORY

SPECIFICATIONS

15 V DUAL SUPPLY

V_{DD} = +15 V ± 10%, V_{SS} = −15 V ± 10%, GND = 0 V, unless otherwise noted.

Table 2.

Parameter	+25°C	−40°C to +85°C	−40°C to +125°C[1]	Unit	Test Conditions/Comments
ANALOG SWITCH					
Analog Signal Range			V_{SS} to V_{DD}	V	
On Resistance (R_{ON})	4			Ω typ	V_S = ±10 V, I_S = −10 mA; see Figure 26
	4.7	5.7	6.7	Ω max	V_{DD} = +13.5 V, V_{SS} = −13.5 V
On Resistance Match Between Channels (ΔR$_{ON}$)	0.2			Ω typ	V_S = ±10 V, I_S = −10 mA
	0.78	0.85	1.1	Ω max	
On-Resistance Flatness ($R_{FLAT(ON)}$)	0.5			Ω typ	V_S = ±10 V, I_S = −10 mA
	0.72	0.77	0.92	Ω max	
LEAKAGE CURRENTS					V_{DD} = +16.5 V, V_{SS} = −16.5 V
Source Off Leakage, I$_S$ (Off)	±0.04			nA typ	V_S = ±10 V, V_D = ∓10 V; see Figure 27
	±0.2	±0.6	±5	nA max	
Drain Off Leakage, I$_D$ (Off)	±0.04			nA typ	V_S = ±10 V, V_D = ∓10 V; see Figure 27
	±0.45	±2	±30	nA max	
Channel On Leakage, I$_D$, I$_S$ (On)	±0.1			nA typ	V_S = V_D = ±10 V; see Figure 28
	±1.5	±3	±30	nA max	
DIGITAL INPUTS					
Input High Voltage, V$_{INH}$			2.0	V min	
Input Low Voltage, V$_{INL}$			0.8	V max	
Input Current	±0.005			µA typ	V_{IN} = V_{GND} or V_{DD}
			±0.1	µA max	
Digital Input Capacitance, C$_{IN}$	4			pF typ	
DYNAMIC CHARACTERISTICS[2]					
Transition Time, t$_{TRANSITION}$	140			ns typ	R_L = 100 Ω, C_L = 35 pF
	170	210	240	ns max	V_S = 10 V, see Figure 29
Break-Before-Make Time Delay, t$_{BBM}$	50			ns typ	R_L = 100 Ω, C_L = 35 pF
			30	ns min	V_{S1} = V_{S2} = 10 V; see Figure 30
t$_{ON}$ (EN)	100			ns typ	R_L = 100 Ω, C_L = 35 pF
	120	150	165	ns max	V_S = 10 V; see Figure 31
t$_{OFF}$ (EN)	100			ns typ	R_L = 100 Ω, C_L = 35 pF
	120	150	170	ns max	V_S = 10 V; see Figure 31
Charge Injection	−50			pC typ	V_S = 0 V, R_S = 0 Ω, C_L = 1 nF; see Figure 32
Off Isolation	−70			dB typ	R_L = 50 Ω, C_L = 5 pF, f = 1 MHz; see Figure 33
Channel-to-Channel Crosstalk	−70			dB typ	R_L = 50 Ω, C_L = 5 pF, f = 1 MHz; see Figure 34
Total Harmonic Distortion Plus Noise (THD + N)	0.025			% typ	R_L = 110 Ω, 15 V p-p, f = 20 Hz to 20 kHz; see Figure 36
−3 dB Bandwidth					R_L = 50 Ω, C_L = 5 pF; see Figure 35
ADG1408	60			MHz typ	
ADG1409	115			MHz typ	
Insertion Loss	0.24			dB typ	R_L = 50 Ω, C_L = 5 pF, f = 1 MHz; see Figure 35
C$_S$ (Off)	14			pF typ	f = 1 MHz
C$_D$ (Off)					f = 1 MHz
ADG1408	80			pF typ	
ADG1409	40			pF typ	

Parameter	+25°C	−40°C to +85°C	−40°C to +125°C[1]	Unit	Test Conditions/Comments
C_D, C_S (On)					f = 1 MHz
ADG1408	135			pF typ	
ADG1409	90			pF typ	
POWER REQUIREMENTS					V_{DD} = +16.5 V, V_{SS} = −16.5 V
I_{DD}	0.002			µA typ	Digital inputs = 0 V or V_{DD}
			1	µA max	
	220			µA typ	Digital inputs = 5 V
			380	µA max	
I_{SS}	0.002			µA typ	Digital inputs = 0 V, 5 V or V_{DD}
			1	µA max	
V_{DD}/V_{SS}			±4.5/±16.5	V min/max	

[1] Temperature range: Y version: −40°C to +125°C.
[2] Guaranteed by design, not subject to production test.

12 V SINGLE SUPPLY

V_{DD} = 12 V ± 10%, V_{SS} = 0 V, GND = 0 V, unless otherwise noted.

Table 3.

Parameter	+25°C	−40°C to +85°C	−40°C to +125°C[1]	Unit	Test Conditions/Comments
ANALOG SWITCH					
Analog Signal Range			0 to V_{DD}	V	
On Resistance (R_{ON})	6			Ω typ	V_S = 0 V to 10 V, I_S = −10 mA; see Figure 26
	8	9.5	11.2	Ω max	V_{DD} = 10.8 V, V_{SS} = 0 V
On-Resistance Match Between Channels (ΔR_{ON})	0.2			Ω typ	V_S = 0 V to 10 V, I_S = −10 mA
	0.82	0.85	1.1	Ω max	
On-Resistance Flatness ($R_{FLAT(ON)}$)	1.5			Ω typ	V_S = 0 V to 10 V, I_S = −10 mA
	2.5	2.5	2.8	Ω max	
LEAKAGE CURRENTS					V_{DD} = 13.2 V
Source Off Leakage, I_S (Off)	±0.04			nA typ	V_S = 1 V/10 V, V_D = 10 V/1 V; see Figure 27
	±0.2	±0.6	±5	nA max	
Drain Off Leakage, I_D (Off)	±0.04			nA typ	V_S = 1 V/10 V, V_D = 10 V/1 V; see Figure 27
	±0.45	±1	±37	nA max	
Channel On Leakage, I_D, I_S (On)	±0.06			nA typ	V_S = V_D = 1 V or 10 V; see Figure 28
	±0.44	±1.3	±32	nA max	
DIGITAL INPUTS					
Input High Voltage, V_{INH}			2.0	V min	
Input Low Voltage, V_{INL}			0.8	V max	
Input Current	±0.005			µA typ	V_{IN} = V_{GND} or V_{DD}
			±0.1	µA max	
Digital Input Capacitance, C_{IN}	5			pF typ	
DYNAMIC CHARACTERISTICS[2]					
Transition Time, $t_{TRANSITION}$	200			ns typ	R_L = 100 Ω, C_L = 35 pF
	260	330	380	ns max	V_S = 8 V; see Figure 29
Break-Before-Make Time Delay, t_{BBM}	90			ns typ	R_L = 100 Ω, C_L = 35 pF
			40	ns min	V_{S1} = V_{S2} = 8 V; see Figure 30
t_{ON} (EN)	160			ns typ	R_L = 100 Ω, C_L = 35 pF
	210	250	285	ns max	V_S = 8 V; see Figure 31
t_{OFF} (EN)	115			ns typ	R_L = 100 Ω, C_L = 35 pF
	145	180	200	ns max	V_S = 8 V; see Figure 31
Charge Injection	−12			pC typ	V_S = 6 V, R_S = 0 Ω, C_L = 1 nF; see Figure 32
Off Isolation	−70			dB typ	R_L = 50 Ω, C_L = 5 pF, f = 1 MHz; see Figure 33
Channel-to-Channel Crosstalk	−70			dB typ	R_L = 50 Ω, C_L = 5 pF, f = 1 MHz; see Figure 34
−3 dB Bandwidth					R_L = 50 Ω, C_L = 5 pF; see Figure 35
ADG1408	36			MHz typ	
ADG1409	72			MHz typ	
Insertion Loss	0.5			dB typ	R_L = 50 Ω, C_L = 5 pF, f = 1 MHz; see Figure 35
C_S (Off)	25			pF typ	f = 1 MHz
C_D (Off)					f = 1 MHz
ADG1408	165			pF typ	
ADG1409	80			pF typ	
C_D, C_S (On)					f = 1 MHz
ADG1408	200			pF typ	
ADG1409	120			pF typ	

Parameter	+25°C	−40°C to +85°C	−40°C to +125°C[1]	Unit	Test Conditions/Comments
POWER REQUIREMENTS					V_{DD} = 13.2 V
I_{DD}	0.002			µA typ	Digital inputs = 0 V or V_{DD}
			1	µA max	
	220			µA typ	Digital inputs = 5 V
			380	µA max	
V_{DD}			5/16.5	V min/max	V_{SS} = 0 V, GND = 0 V

[1] Temperature range for Y version: −40°C to +125°C.
[2] Guaranteed by design, not subject to production test.

5 V DUAL SUPPLY

V_{DD} = +5 V ± 10%, V_{SS} = −5 V ± 10%, GND = 0 V, unless otherwise noted.

Table 4.

Parameter	+25°C	−40°C to +85°C	−40°C to +125°C[1]	Unit	Test Conditions/Comments
ANALOG SWITCH					
Analog Signal Range			V_{SS} to V_{DD}	V	
On Resistance (R_{ON})	7			Ω typ	V_S = ±4.5 V, I_S = −10 mA; see Figure 26
	9	10.5	12	Ω max	V_{DD} = +4.5 V, V_{SS} = −4.5 V
On-Resistance Match Between Channels (ΔR_{ON})	0.3			Ω typ	V_S = ±4.5 V, I_S = −10 mA
	0.78	0.91	1.1	Ω max	
On-Resistance Flatness ($R_{FLAT(ON)}$)	1.5			Ω typ	V_S = ±4.5 V; I_S = −10 mA
	2.5	2.5	3	Ω max	
LEAKAGE CURRENTS					V_{DD} = +5.5 V, V_{SS} = −5.5 V
Source Off Leakage, I_S (Off)	±0.02			nA typ	V_S = ±4.5 V, V_D = ∓4.5 V; see Figure 27
	±0.2	±0.6	±5	nA max	
Drain Off Leakage, I_D (Off)	±0.02			nA typ	V_S = ±4.5 V, V_D = ∓4.5 V; see Figure 27
	±0.45	±0.8	±20	nA max	
Channel On Leakage, I_D, I_S (On)	±0.04			nA typ	V_S = V_D = ±4.5 V; see Figure 28
	±0.3	±1.1	±22	nA max	
DIGITAL INPUTS					
Input High Voltage, V_{INH}			2.0	V min	
Input Low Voltage, V_{INL}			0.8	V max	
Input Current	±0.005			μA typ	V_{IN} = V_{GND} or V_{DD}
			±0.1	μA max	
Digital Input Capacitance, C_{IN}	5			pF typ	
DYNAMIC CHARACTERISTICS[2]					
Transition Time, $t_{TRANSITION}$	330			ns typ	R_L = 100 Ω, C_L = 35 pF
	440	530	550	ns max	V_S = 5 V; see Figure 29
Break-Before-Make Time Delay, t_{BBM}	100			ns typ	R_L = 100 Ω, C_L = 35 pF
			50	ns min	V_{S1} = V_{S2} = 5 V; see Figure 30
t_{ON} (EN)	245			ns typ	R_L = 100 Ω, C_L = 35 pF
	330	400	440	ns max	V_S = 5 V; see Figure 31
t_{OFF} (EN)	215			ns typ	R_L = 100 Ω, C_L = 35 pF
	285	335	370	ns max	V_S = 5 V; see Figure 31
Charge Injection	−10			pC typ	V_S = 0 V, R_S = 0 Ω, C_L = 1 nF; see Figure 32
Off Isolation	−70			dB typ	R_L = 50 Ω, C_L = 5 pF, f = 1 MHz; see Figure 33
Channel-to-Channel Crosstalk	−70			dB typ	R_L = 50 Ω, C_L = 5 pF, f = 1 MHz; see Figure 34
Total Harmonic Distortion Plus Noise (THD + N)	0.06			% typ	R_L = 110 Ω, 5 V p-p, f = 20 Hz to 20 kHz; see Figure 36
−3 dB Bandwidth					R_L = 50 Ω, C_L = 5 pF; see Figure 35
ADG1408	40			MHz typ	
ADG1409	80			MHz typ	
Insertion Loss	0.5			dB typ	R_L = 50 Ω, C_L = 5 pF, f = 1 MHz; see Figure 35
C_S (Off)	20			pF typ	f = 1 MHz
C_D (Off)					f = 1 MHz
ADG1408	130			pF typ	
ADG1409	65			pF typ	
C_D, C_S (On)					f = 1 MHz
ADG1408	180			pF typ	
ADG1409	120			pF typ	

Parameter	+25°C	−40°C to +85°C	−40°C to +125°C[1]	Unit	Test Conditions/Comments
POWER REQUIREMENTS					V_{DD} = +5.5 V, V_{SS} = −5.5 V
I_{DD}	0.001			µA typ	Digital inputs = 0 V or V_{DD}
			1	µA max	
I_{SS}	0.001			µA typ	Digital inputs = 0 V, 5 V or V_{DD}
			1	µA max	
V_{DD}/V_{SS}			±4.5/±16.5	V min/max	

[1] Temperature range for Y version: −40°C to +125°C.
[2] Guaranteed by design, not subject to production test.

CONTINUOUS CURRENT PER CHANNEL, S OR D

Table 5.

Parameter	25°C	85°C	125°C	Unit	Test Conditions/Comments
CONTINUOUS CURRENT, S or D[1]					
15 V Dual Supply					V_{DD} = +13.5 V, V_{SS} = −13.5 V
ADG1408	190	105	50	mA max	
ADG1409	140	85	45	mA max	
12 V Single Supply					V_{DD} = 10.8 V, V_{SS} = 0 V
ADG1408	160	95	50	mA max	
ADG1409	120	75	40	mA max	
5 V Dual Supply					V_{DD} = +4.5 V, V_{SS} = −4.5 V
ADG1408	155	90	45	mA max	
ADG1409	115	70	40	mA max	

[1] Guaranteed by design, not subject to production test.

ABSOLUTE MAXIMUM RATINGS

$T_A = 25°C$, unless otherwise noted.

Table 6.

Parameter	Rating
V_{DD} to V_{SS}	35 V
V_{DD} to GND	−0.3 V to +25 V
V_{SS} to GND	+0.3 V to −25 V
Analog Inputs[1]	V_{SS} − 0.3 V to V_{DD} + 0.3 V or 30 mA, whichever occurs first
Digital Inputs[1]	GND − 0.3 V to V_{DD} + 0.3 V or 30 mA, whichever occurs first
Continuous Current, S or D	Table 5 data + 10%
Peak Current, S or D (Pulsed at 1 ms, 10% Duty Cycle Maximum)	350 mA
Operating Temperature Range Industrial (Y Version)	−40°C to +125°C
Storage Temperature Range	−65°C to +150°C
Junction Temperature	150°C
Reflow Soldering Peak Temperature (RoHS Compliant)	260(+0/−5)°C

[1] Overvoltages at A, EN, S, or D are clamped by internal diodes. Current should be limited to the maximum ratings given.

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

Only one absolute maximum rating can be applied at any one time.

THERMAL RESISTANCE

$θ_{JA}$ is specified for the worst-case conditions, that is, a device soldered in a circuit board for surface-mount packages.

Table 7. Thermal Resistance

Package Type	$θ_{JA}$	$θ_{JC}$	Unit
16-Lead TSSOP	150.4	50	°C/W
16-Lead LFCSP	30.4		°C/W

ESD CAUTION

ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

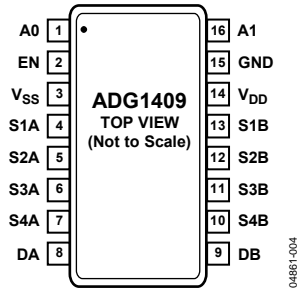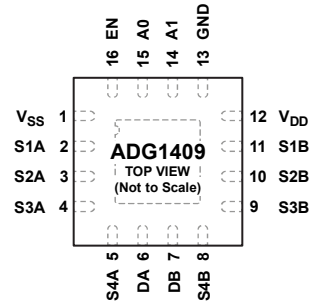# PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS
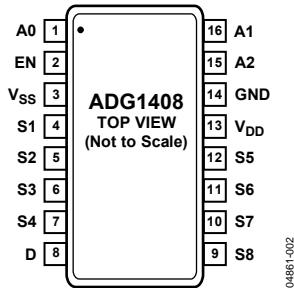
Figure 2. ADG1408 Pin Configuration (TSSOP)
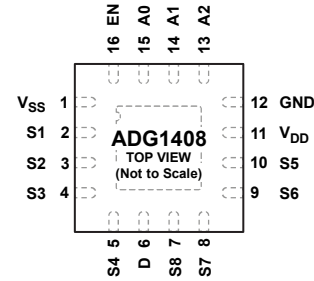
NOTES
1. THE EXPOSED PAD IS CONNECTED INTERNALLY. FOR INCREASED RELIABILITY OF THE SOLDER JOINTS AND MAXIMUM THERMAL CAPABILITY, IT IS RECOMMENDED THAT THE PAD BE SOLDERED TO THE SUBSTRATE, V$_{SS}$.

Figure 3. ADG1408 Pin Configuration (LFCSP)

Table 8. ADG1408 Pin Function Descriptions

Pin No.		Mnemonic	Description
TSSOP	LFCSP		
1	15	A0	Logic Control Input.
2	16	EN	Active High Digital Input. When low, the device is disabled and all switches are off. When high, Ax logic inputs determine on switches.
3	1	V$_{SS}$	Most Negative Power Supply Potential. In single supply applications, it can be connected to ground.
4	2	S1	Source Terminal 1. Can be an input or an output.
5	3	S2	Source Terminal 2. Can be an input or an output.
6	4	S3	Source Terminal 3. Can be an input or an output.
7	5	S4	Source Terminal 4. Can be an input or an output.
8	6	D	Drain Terminal. Can be an input or an output.
9	7	S8	Source Terminal 8. Can be an input or an output.
10	8	S7	Source Terminal 7. Can be an input or an output.
11	9	S6	Source Terminal 6. Can be an input or an output.
12	10	S5	Source Terminal 5. Can be an input or an output.
13	11	V$_{DD}$	Most Positive Power Supply Potential.
14	12	GND	Ground (0 V) Reference.
15	13	A2	Logic Control Input.
16	14	A1	Logic Control Input.
Not applicable	0	EPAD	Exposed Pad. The exposed pad is connected internally. For increased reliability of the solder joints and maximum thermal capability, it is recommended that the pad be soldered to the substrate, V$_{SS}$.

Table 9. ADG1408 Truth Table

A2	A1	A0	EN	On Switch
X	X	X	0	None
0	0	0	1	1
0	0	1	1	2
0	1	0	1	3
0	1	1	1	4
1	0	0	1	5
1	0	1	1	6
1	1	0	1	7
1	1	1	1	8

Figure 4. *ADG1409* Pin Configuration (TSSOP)

NOTES
1. THE EXPOSED PAD IS CONNECTED INTERNALLY. FOR INCREASED RELIABILITY OF THE SOLDER JOINTS AND MAXIMUM THERMAL CAPABILITY, IT IS RECOMMENDED THAT THE PAD BE SOLDERED TO THE SUBSTRATE, V$_{SS}$.

Figure 5. *ADG1409* Pin Configuration (LFCSP)

Table 10. ADG1409 Pin Function Descriptions

Pin No.			
TSSOP	**LFCSP**	**Mnemonic**	**Description**
1	15	A0	Logic Control Input.
2	16	EN	Active High Digital Input. When low, the device is disabled and all switches are off. When high, Ax logic inputs determine on switches.
3	1	V$_{SS}$	Most Negative Power Supply Potential. In single supply applications, it can be connected to ground.
4	2	S1A	Source Terminal 1A. Can be an input or an output.
5	3	S2A	Source Terminal 2A. Can be an input or an output.
6	4	S3A	Source Terminal 3A. Can be an input or an output.
7	5	S4A	Source Terminal 4A. Can be an input or an output.
8	6	DA	Drain Terminal A. Can be an input or an output.
9	7	DB	Drain Terminal B. Can be an input or an output.
10	8	S4B	Source Terminal 4B. Can be an input or an output.
11	9	S3B	Source Terminal 3B. Can be an input or an output.
12	10	S2B	Source Terminal 2B. Can be an input or an output.
13	11	S1B	Source Terminal 1B. Can be an input or an output.
14	12	V$_{DD}$	Most Positive Power Supply Potential.
15	13	GND	Ground (0 V) Reference.
16	14	A1	Logic Control Input.
Not applicable	0	EPAD	Exposed Pad. The exposed pad is connected internally. For increased reliability of the solder joints and maximum thermal capability, it is recommended that the pad be soldered to the substrate, V$_{SS}$.

Table 11. ADG1409 Truth Table

A1	A0	EN	On Switch Pair
X	X	0	None
0	0	1	1
0	1	1	2
1	0	1	3
1	1	1	4

TYPICAL PERFORMANCE CHARACTERISTICS
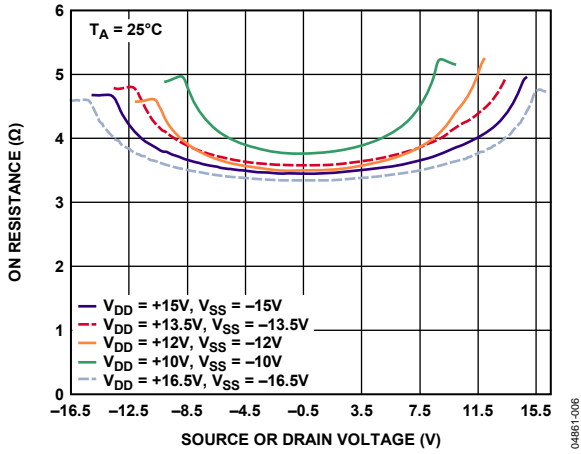
Figure 6. On Resistance vs. V_D, V_S; Dual Supply

Figure 7. On Resistance vs. V_D, V_S; Dual Supply

Figure 8. On Resistance vs. V_D, V_S; Single Supply

Figure 9. On Resistance vs. V_D, V_S for Different Temperatures; 15 V Dual Supply

Figure 10. On Resistance vs. V_D, V_S for Different Temperatures; 5 V Dual Supply
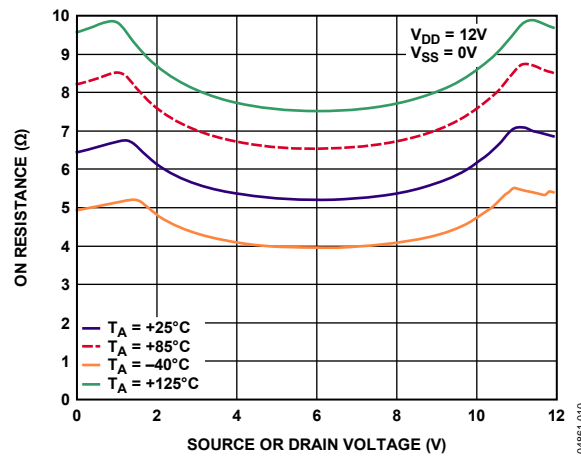
Figure 11. On Resistance vs. V_D, V_S for Different Temperatures; 12 V Single Supply
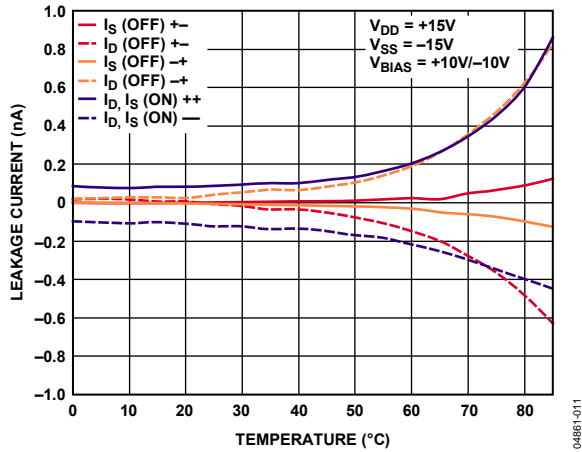
Figure 12. Leakage Current vs. Temperature; 15 V Dual Supply
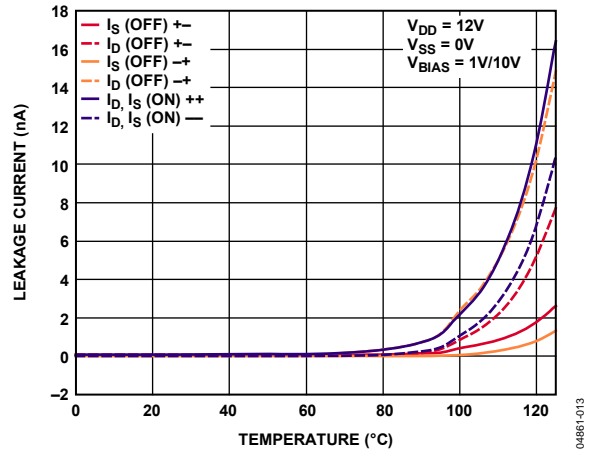
Figure 15. Leakage Current vs. Temperature; 12 V Single Supply
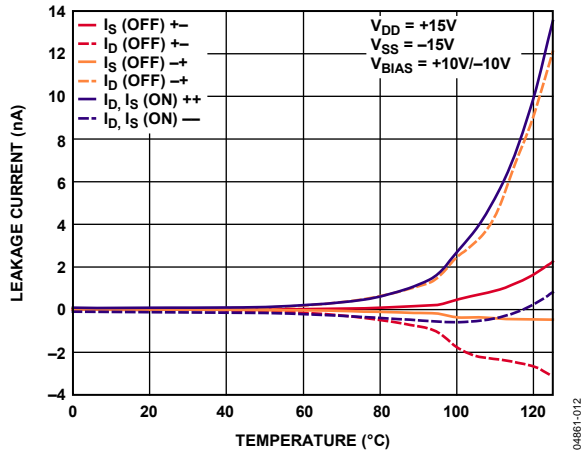
Figure 13. Leakage Current vs. Temperature; 15 V Dual Supply
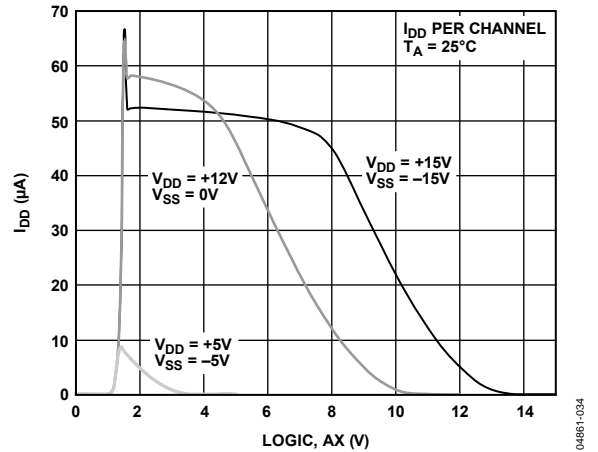
Figure 16. Positive Supply Current vs. Logic Level
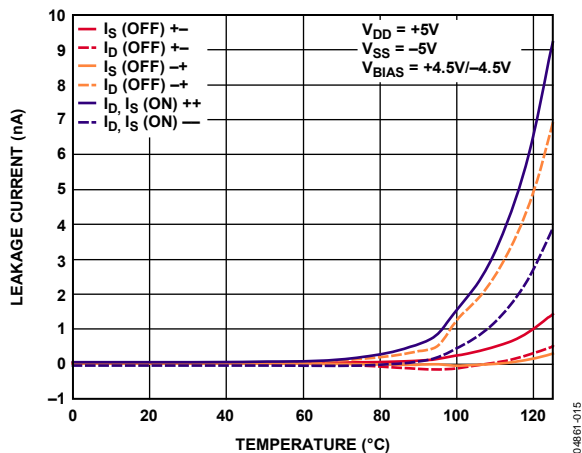
Figure 14. Leakage Current vs. Temperature; 5 V Dual Supply
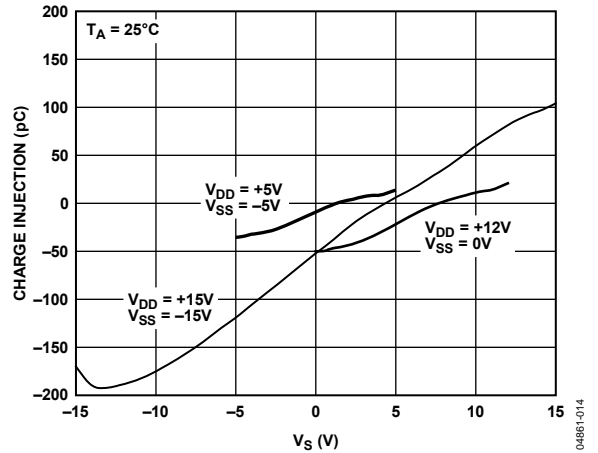
Figure 17. Charge Injection vs. Source Voltage
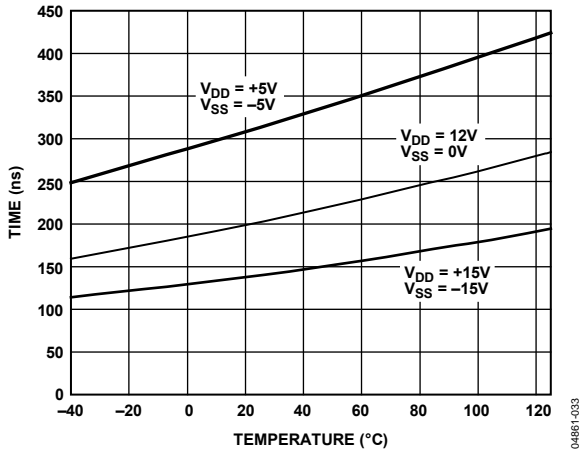
Figure 18. Transition Time vs. Temperature
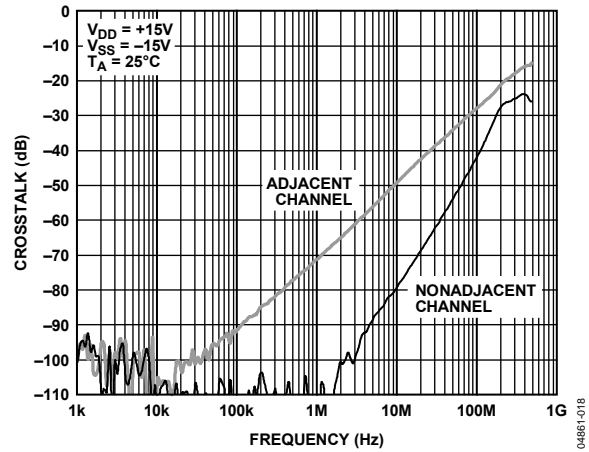
Figure 21. ADG1409 Crosstalk vs. Frequency
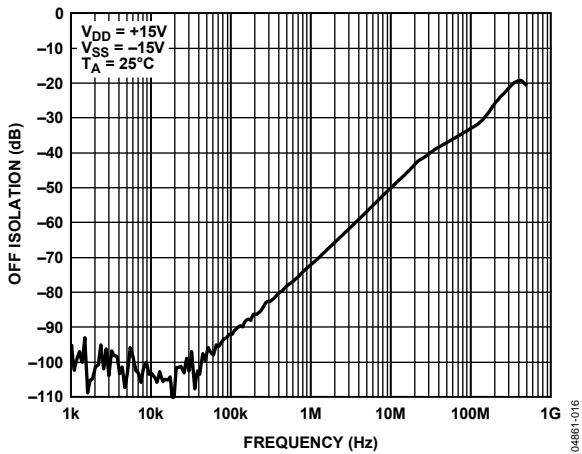
Figure 19. Off Isolation vs. Frequency
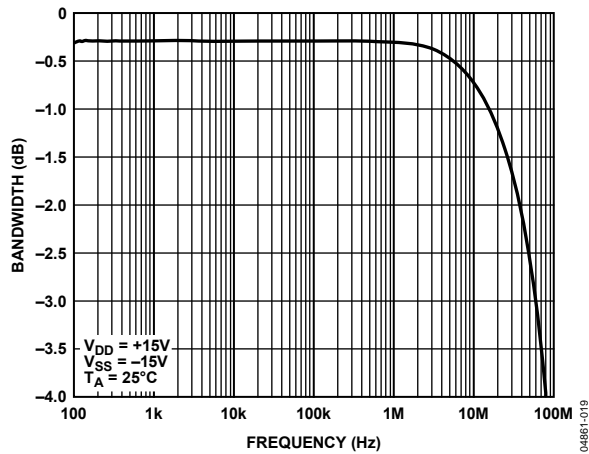
Figure 22. ADG1408 On Response vs. Frequency
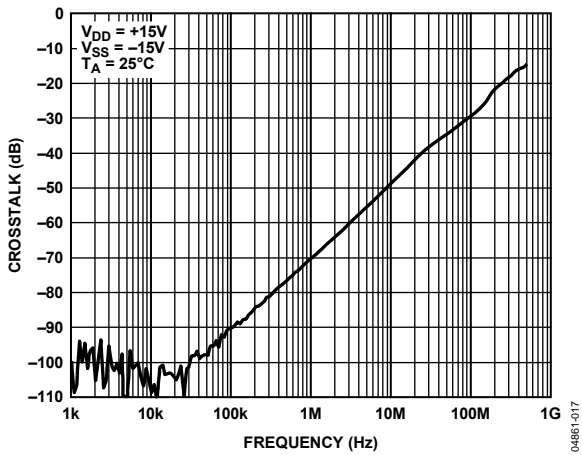
Figure 20. ADG1408 Crosstalk vs. Frequency
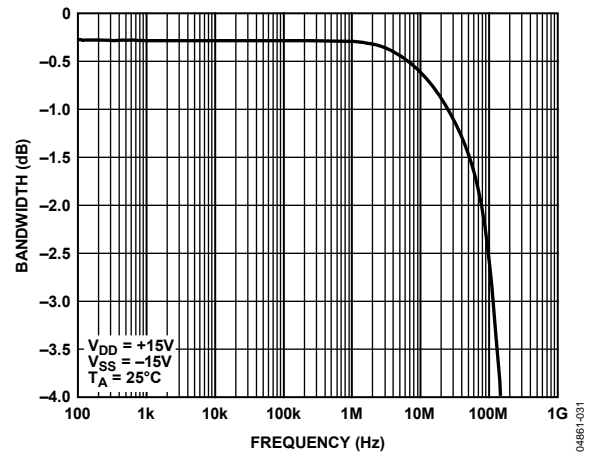
Figure 23. ADG1409 On Response vs. Frequency
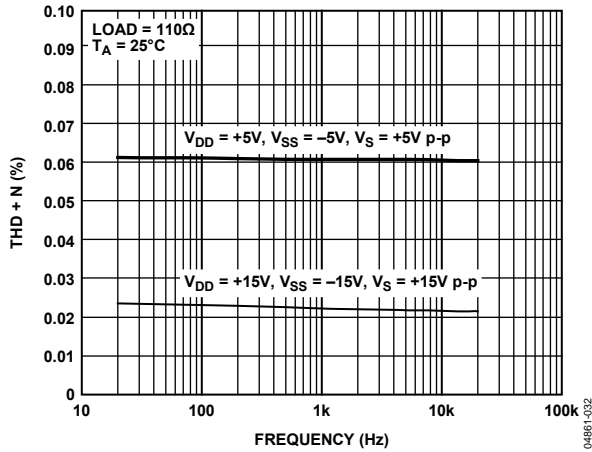
Figure 24. Total Harmonic Distortion Plus Noise vs. Frequency
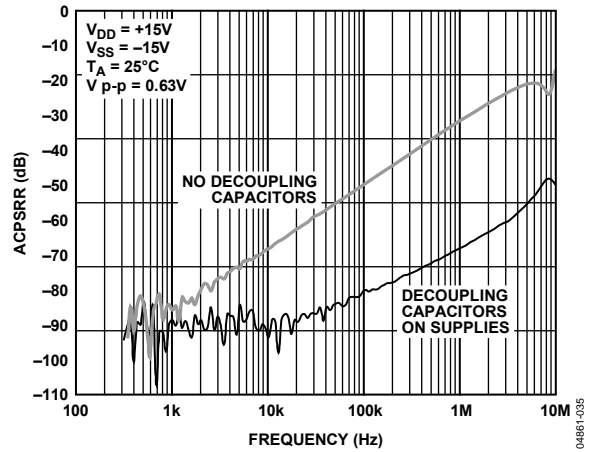
Figure 25. AC Power Supply Rejection Ratio vs. Frequency

TERMINOLOGY

R_{ON}
Ohmic resistance between D and S.

ΔR_{ON}
Difference between the R_{ON} of any two channels.

$R_{FLAT(ON)}$
Flatness is defined as the difference between the maximum and minimum value of on resistance as measured.

I_S (Off)
Source leakage current when the switch is off.

I_D (Off)
Drain leakage current when the switch is off.

I_D, I_S (On)
Channel leakage current when the switch is on.

V_D (V_S)
Analog voltage on Terminal D and Terminal S.

C_S (Off)
Channel input capacitance for off condition.

C_D (Off)
Channel output capacitance for off condition.

C_D, C_S (On)
On switch capacitance.

C_{IN}
Digital input capacitance.

t_{ON} (EN)
Delay time between the 50% and 90% points of the digital input and switch on condition.

t_{OFF} (EN)
Delay time between the 50% and 90% points of the digital input and switch off condition.

$t_{TRANSITION}$
Delay time between the 50% and 90% points of the digital inputs and the switch on condition when switching from one address state to another.

t_{BBM}
Off time measured between the 80% point of both switches when switching from one address state to another.

V_{INL}
Maximum input voltage for Logic 0.

V_{INH}
Minimum input voltage for Logic 1.

I_{INL}, I_{INH}
Input current of the digital input.

I_{DD}
Positive supply current.

I_{SS}
Negative supply current.

Off Isolation
A measure of unwanted signal coupling through an off channel.

Charge Injection
A measure of the glitch impulse transferred from the digital input to the analog output during switching.

Bandwidth
Frequency at which the output is attenuated by 3 dB.

On Response
Frequency response of the on switch.

Total Harmonic Distortion Plus Noise (THD + N)
Ratio of the harmonic amplitude plus noise of the signal to the fundamental.

AC Power Supply Rejection Ratio (ACPSRR)

A measure of the ability of a device to avoid coupling noise and spurious signals that appear on the supply voltage pin to the output of the switch. The dc voltage on the device is modulated by a sine wave of 0.62 V p-p. The ratio of the amplitude of signal on the output to the amplitude of the modulation is the ACPSRR.
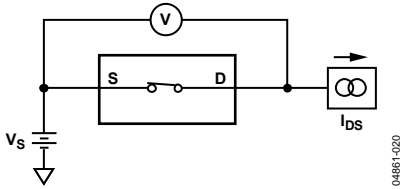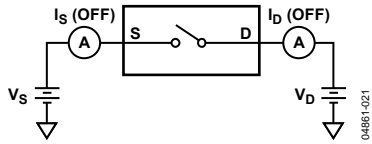
TEST CIRCUITS

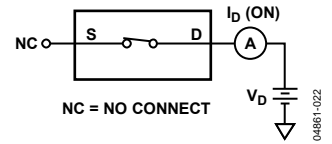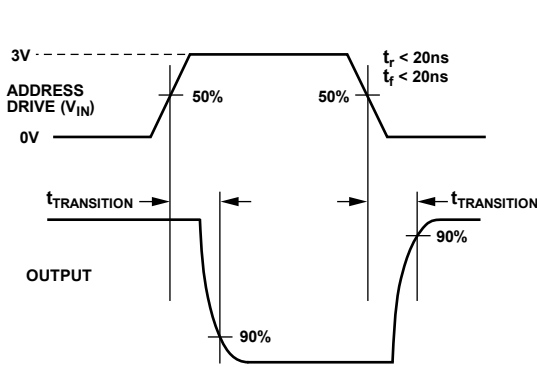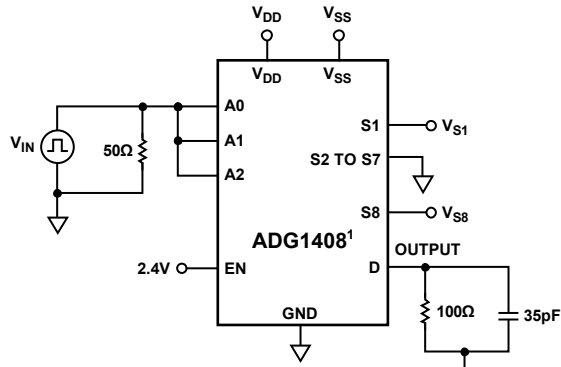Figure 26. On Resistance

Figure 27. Off Leakage

Figure 28. On Leakage

¹SIMILAR CONNECTION FOR ADG1409.

Figure 29. Address to Output Switching Times, $t_{TRANSITION}$

¹SIMILAR CONNECTION FOR ADG1409.
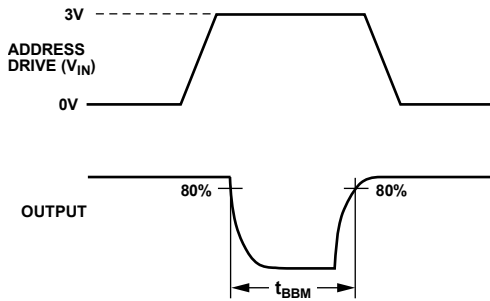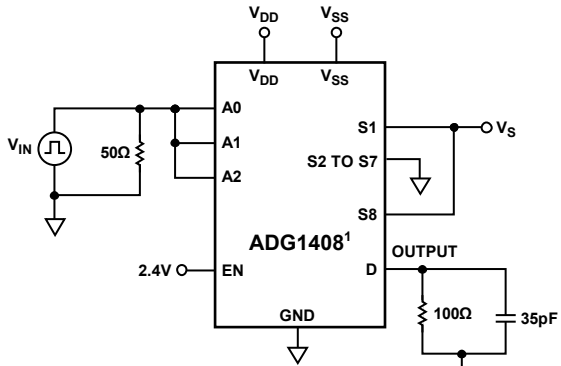
Figure 30. Break-Before-Make Delay, t_{BBM}

¹SIMILAR CONNECTION FOR ADG1409.

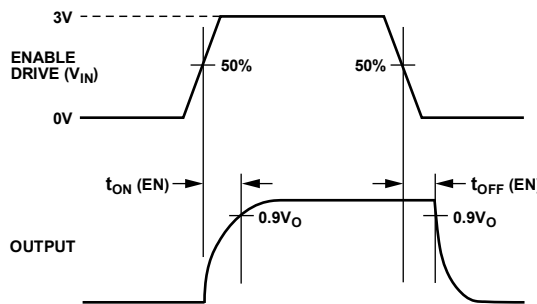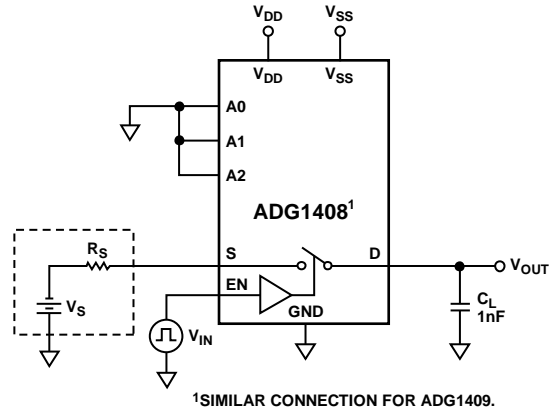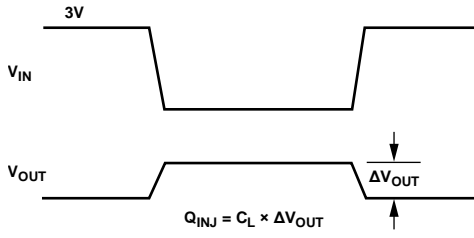Figure 31. Enable Delay, t_{ON} (EN), t_{OFF} (EN)
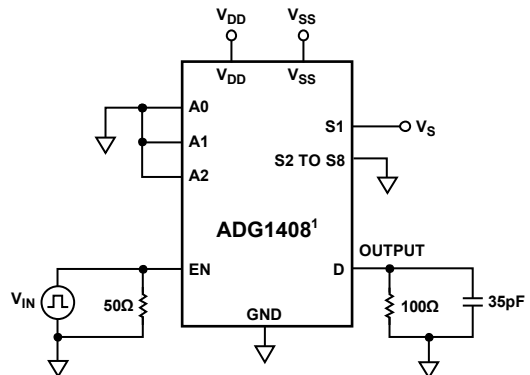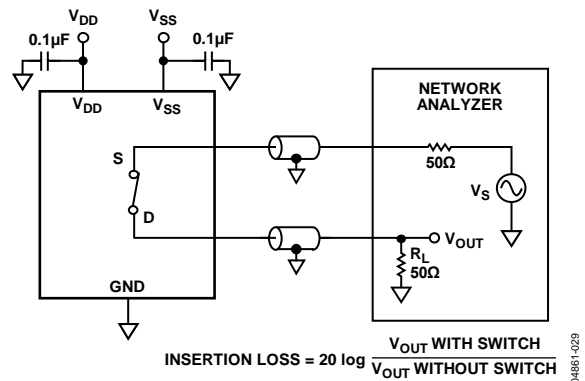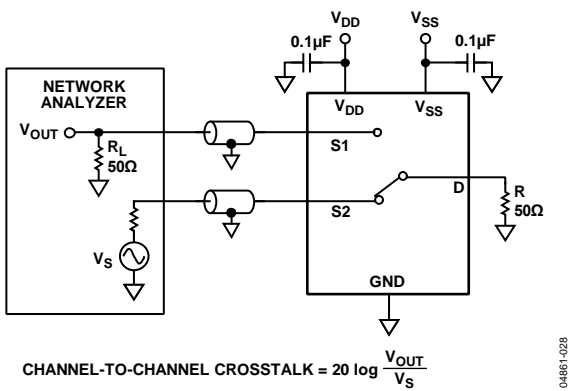
Figure 32. Charge Injection
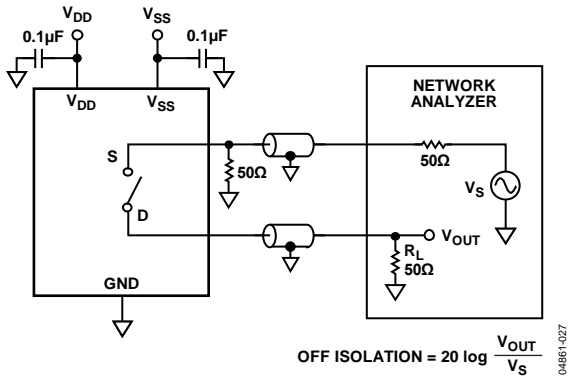
Figure 33. Off Isolation

Figure 34. Channel-to-Channel Crosstalk
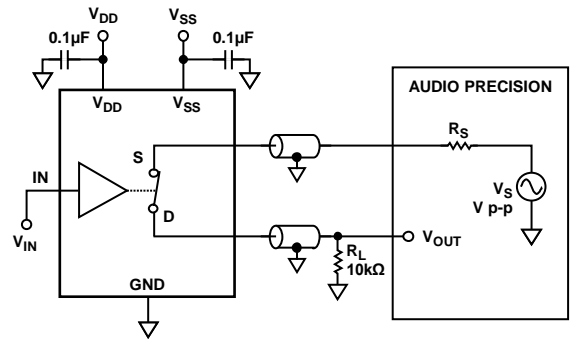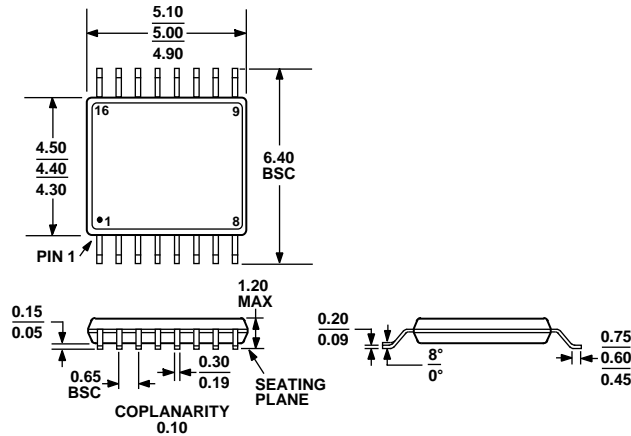

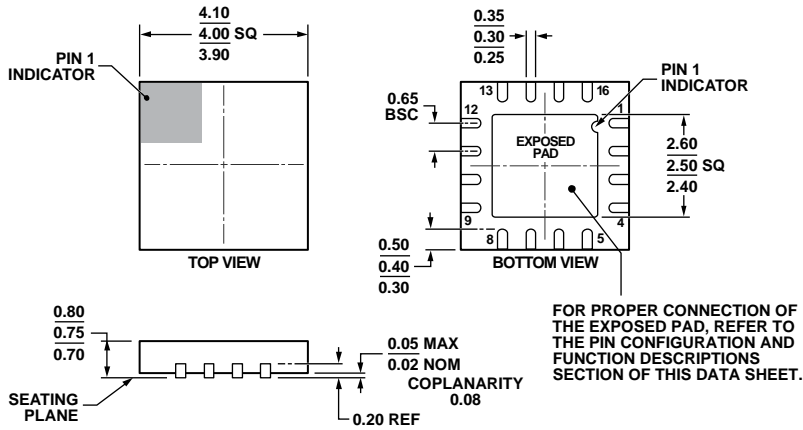Figure 35. Insertion Loss

Figure 36. THD + N

OUTLINE DIMENSIONS

COMPLIANT TO JEDEC STANDARDS MO-153-AB

Figure 37. 16-Lead Thin Shrink Small Outline Package [TSSOP]
(RU-16)
Dimensions shown in millimeters

COMPLIANT TO JEDEC STANDARDS MO-220-WGGC.

Figure 38. 16-Lead Lead Frame Chip Scale Package [LFCSP]
4 mm × 4 mm Body and 0.75 mm Package Height
(CP-16-26)
Dimensions shown in millimeters

ORDERING GUIDE

Model[1]	Temperature Range	Package Description	Package Option
ADG1408YRUZ	−40°C to +125°C	16-Lead Thin Shrink Small Outline Package [TSSOP]	RU-16
ADG1408YRUZ-REEL	−40°C to +125°C	16-Lead Thin Shrink Small Outline Package [TSSOP]	RU-16
ADG1408YRUZ-REEL7	−40°C to +125°C	16-Lead Thin Shrink Small Outline Package [TSSOP]	RU-16
ADG1408YCPZ-REEL7	−40°C to +125°C	16-Lead Lead Frame Chip Scale Package [LFCSP]	CP-16-26
ADG1409YRUZ	−40°C to +125°C	16-Lead Thin Shrink Small Outline Package [TSSOP]	RU-16
ADG1409YRUZ-REEL	−40°C to +125°C	16-Lead Thin Shrink Small Outline Package [TSSOP]	RU-16
ADG1409YRUZ-REEL7	−40°C to +125°C	16-Lead Thin Shrink Small Outline Package [TSSOP]	RU-16
ADG1409YCPZ-REEL7	−40°C to +125°C	16-Lead Lead Frame Chip Scale Package [LFCSP]	CP-16-26

[1] Z = RoHS Compliant Part.

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